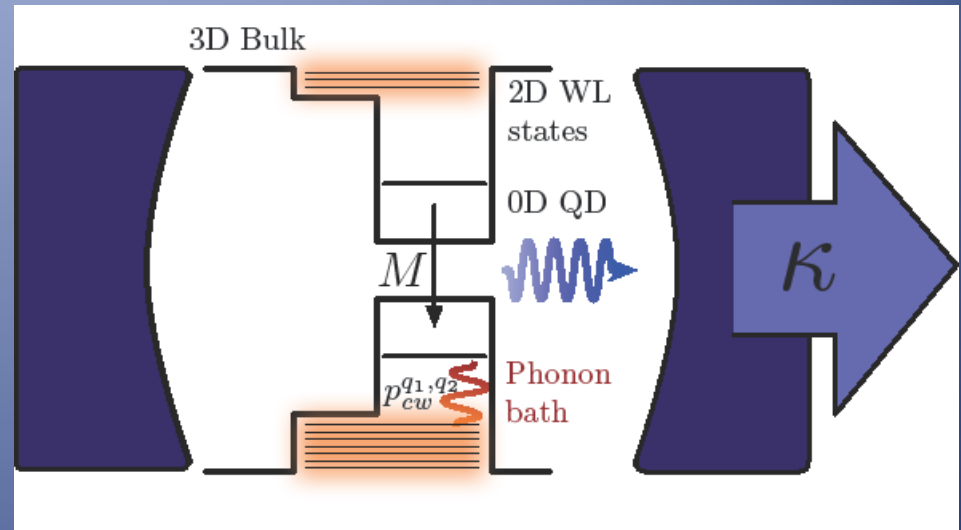


Quantum Light Emission From Cavity Enhanced LEDs

Alexander Carmele, Matthias-Rene Dachner, Julia
Kabuss, Marten Richter, and Andreas Knorr

Semiconductor Quantum Dot dynamics¹:

- 3D bulk: Electron-phonon interaction:
temperature dependent dephasing processes
- 2D WL: Electron-electron interaction
carrier density dependent pumping rate
- 0D QD: Electron-photon interaction
strong coupling for single-photon emission



1. Characterization of the system, e.g. via luminescence experiments
2. LO-phonon assisted carrier scattering from WL into QD states
3. Quantum emission dynamics of QD carriers strongly coupled to a cavity mode

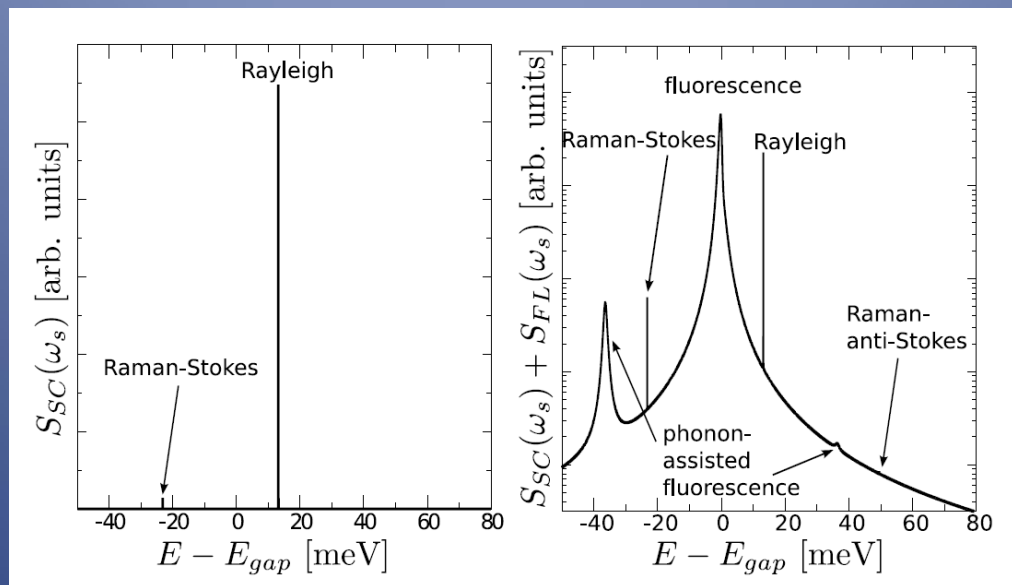
Contribution to Raman spectra:

- Fluorescence
- Rayleigh
- Stokes and Anti-Stokes
- LO - Fluorescence



Information:

- LO-Phonon frequency
- Bandgap frequency



More information with time-resolved spectra:

1. Relaxation time-scales (T1)
2. Differentiation between fluorescence and raman signal on resonant excitation

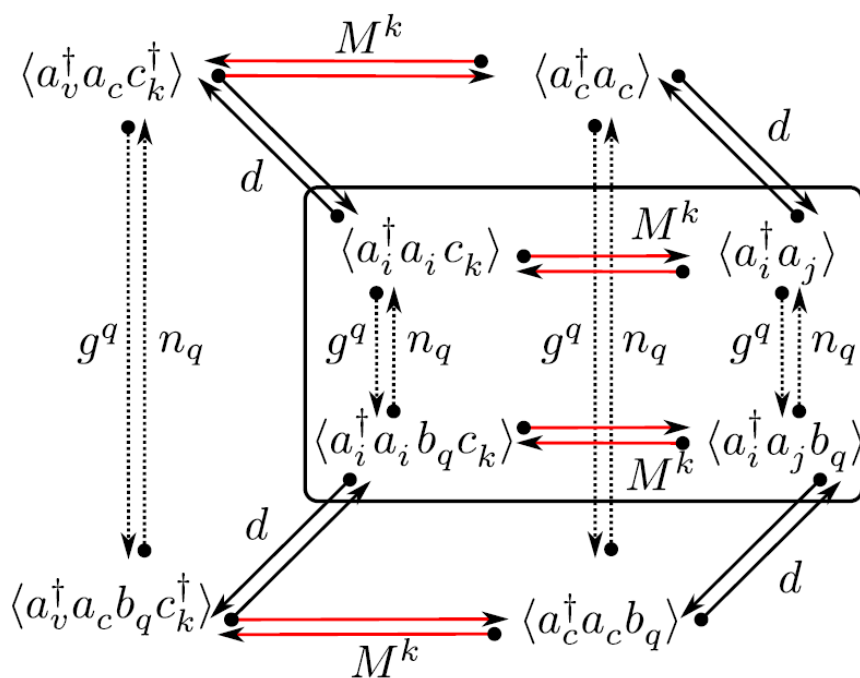
Dynamics of photon coherences with full quantum kinetics in an equation of motion approach¹:

$$\begin{aligned} \partial_t \langle c_{k_1}^\dagger c_{k_2} \rangle &= i(\omega_{k_1} - \omega_{k_2}) \langle c_{k_1}^\dagger c_{k_2} \rangle \\ &+ \frac{i}{\hbar} M_{cv}^{k_1} \langle a_c^\dagger a_v c_{k_2} \rangle - \frac{i}{\hbar} M_{cv}^{k_2*} \langle a_v^\dagger a_c c_{k_1}^\dagger \rangle \end{aligned}$$

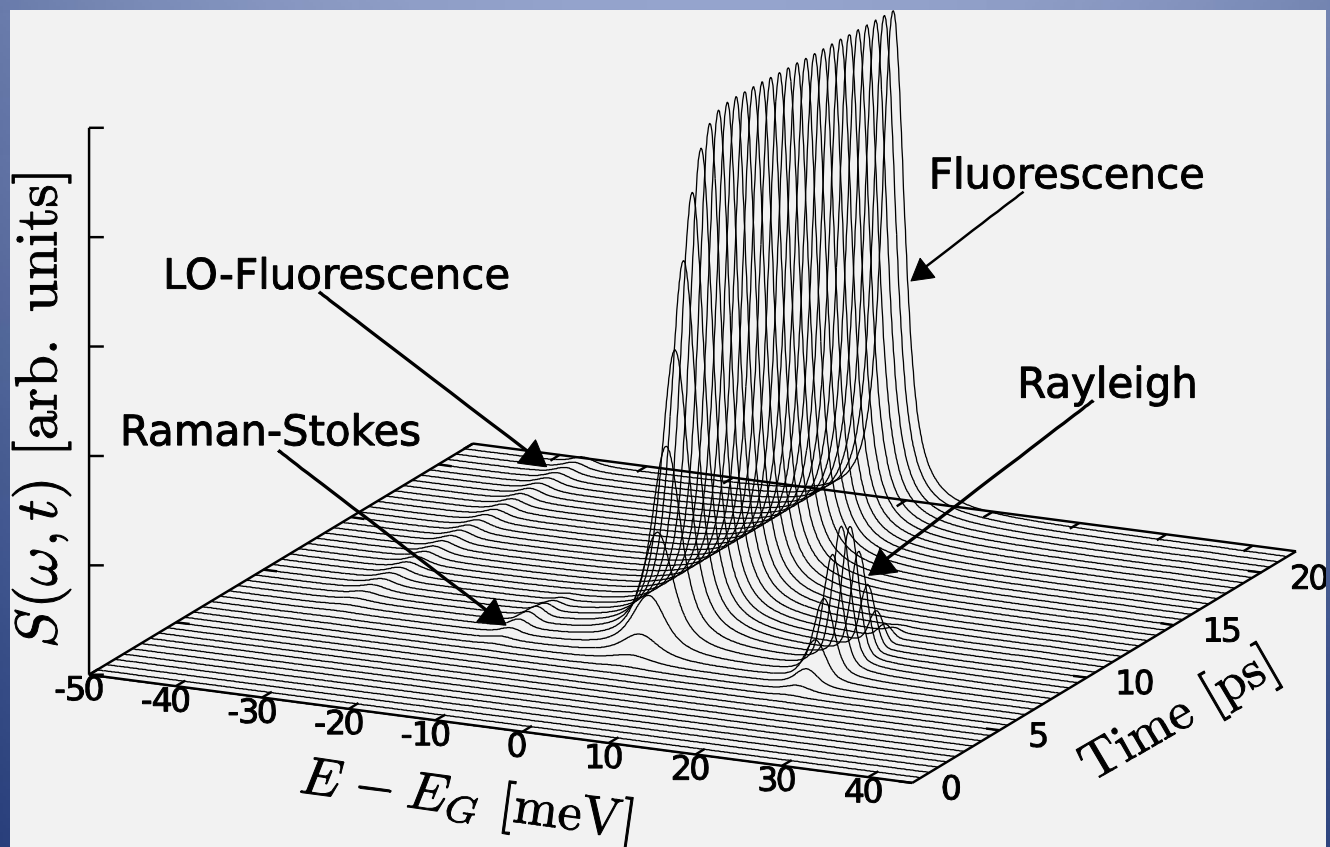
Fluorescence signal:
 2nd & 4th order perturbation

Raman signal:
 6th order perturbation

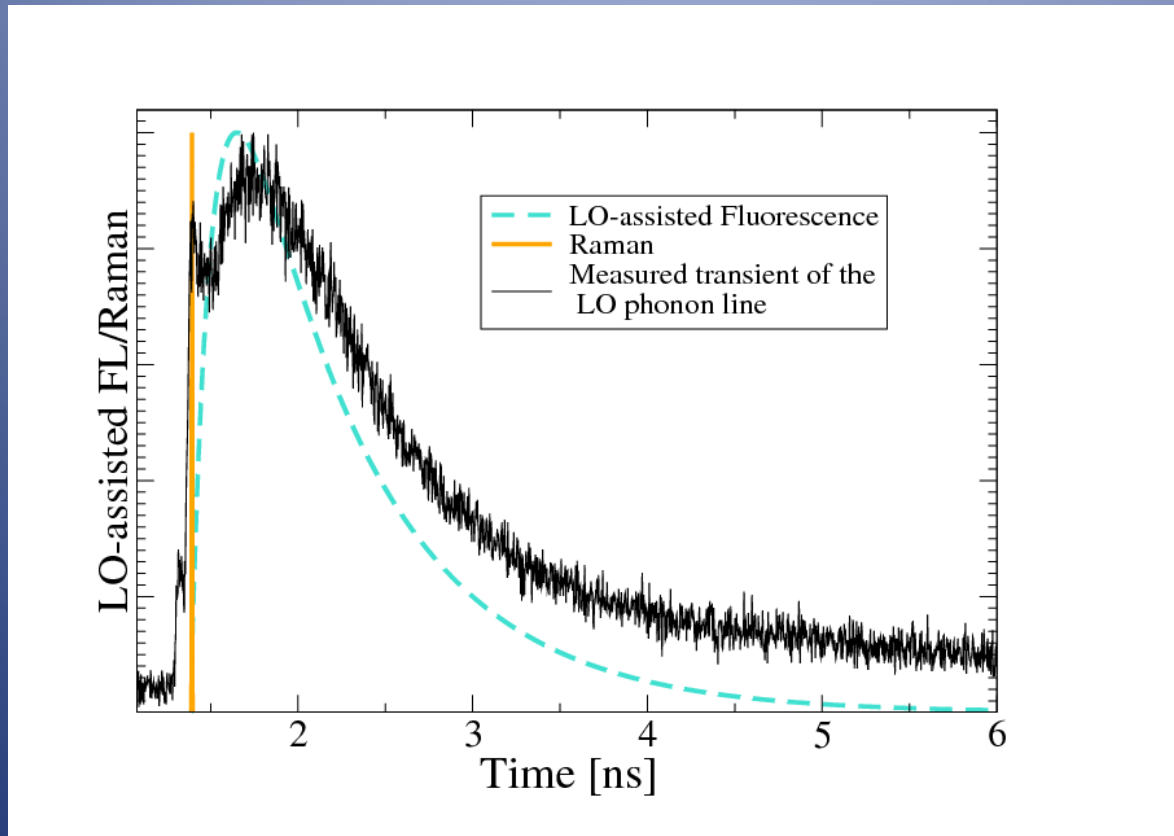
Time-resolution depends on the
 detector



Dynamics of photon coherences with full quantum kinetics in an equation of motion approach¹:



Agreement with measurements done by S. Werner and A. Hoffmann¹:

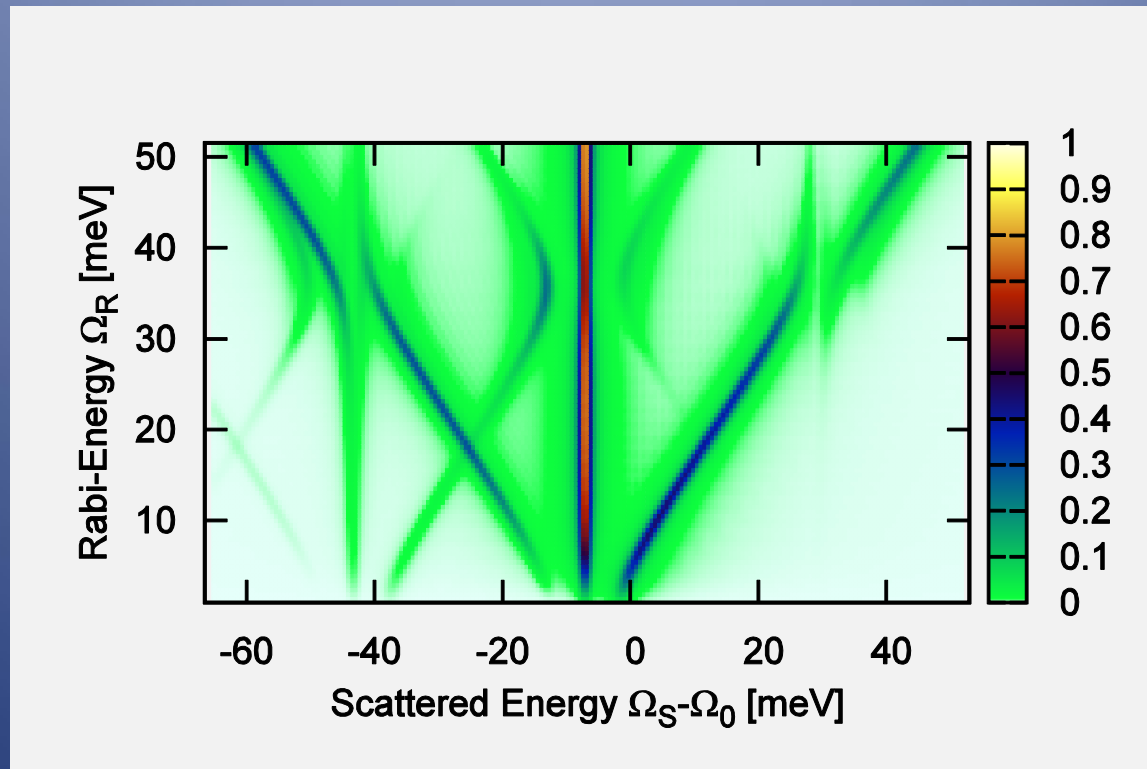


Microscopic theory identifies contributions in spectrum

¹ S. Werner, in preparation (2010)

Equation of motion approach allows exact solution (e.g. induction method¹):

Multi-phonon-assisted quantum emission in the high driving field limit²:

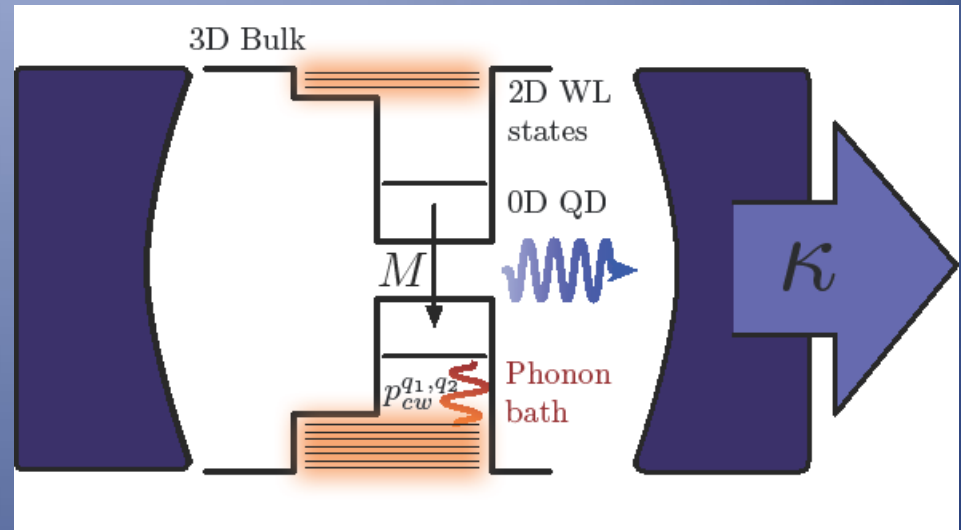


¹ PRL **104**, 156801 (2010)

² Kabuss, in preparation, (2010)

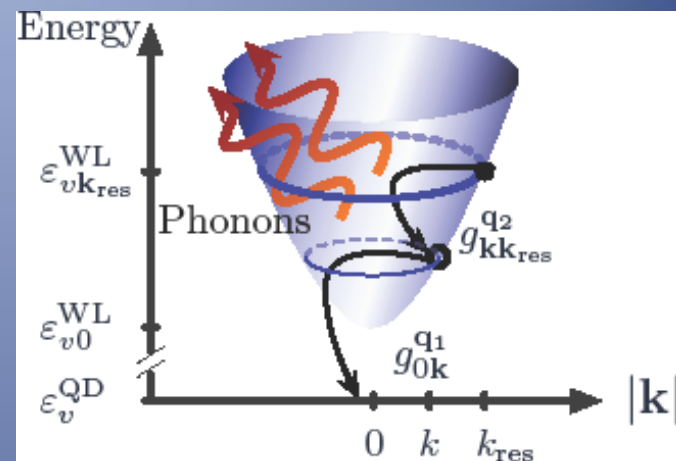
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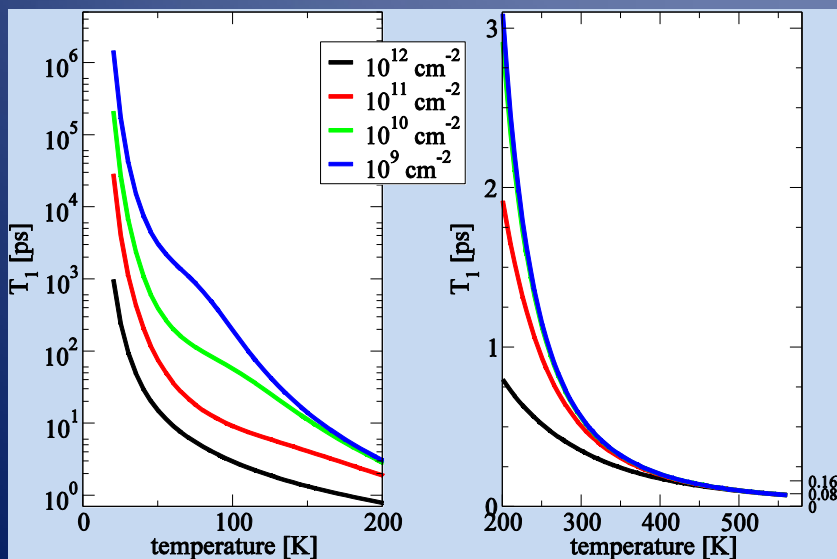


1. Characterization of the system, e.g. via luminescence experiments
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- In an effective Hamiltonian approach a higher order Markovian process is assumed
- Probability of a subprocess depends on how strong the subprocess violates the energy conservation



Relaxation rates¹ in the weak density limit:

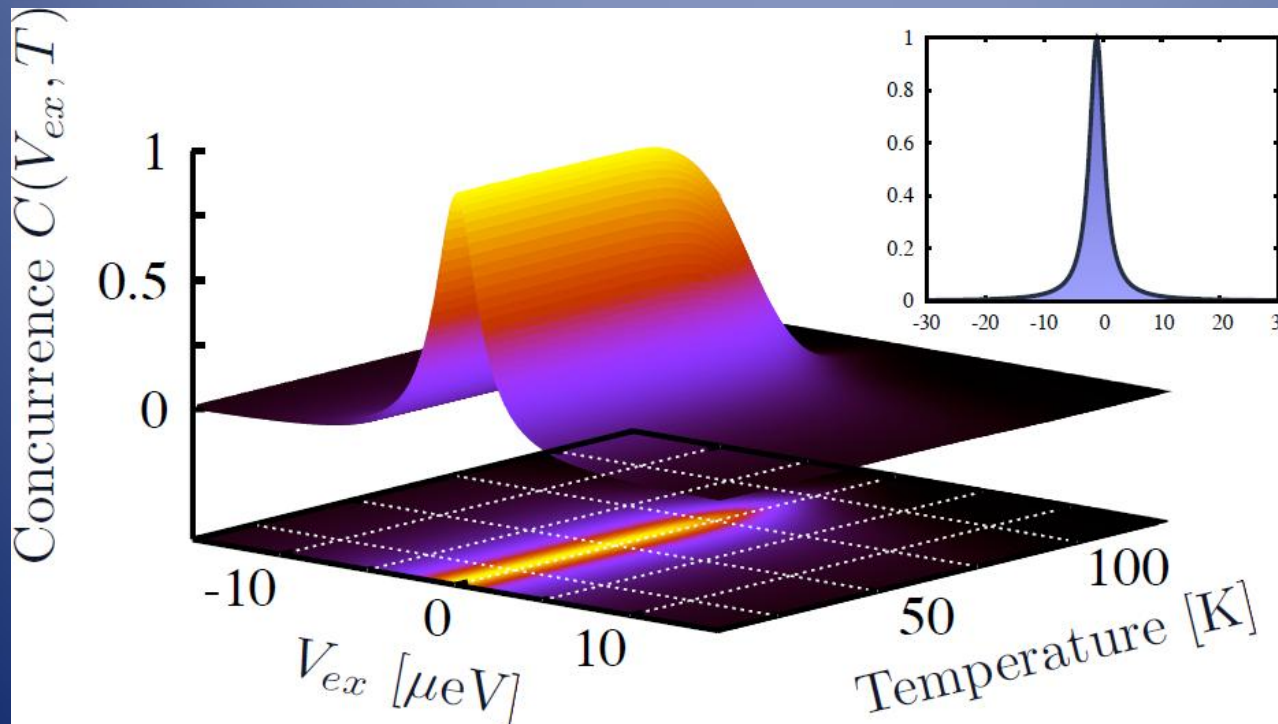


- The relaxation rates depend on the temperature of the bulk material
- Dependence corresponds to a square of the Bose-Einstein-distribution function
- The higher the temperature, the shorter the T1 - Time

Wetting layer contributions lead to an additional dephasing:

$$\Gamma = \Gamma_{rad} + \Gamma_{WL}$$

Multiphonon processes attack the generation of polarization entangled photons¹:



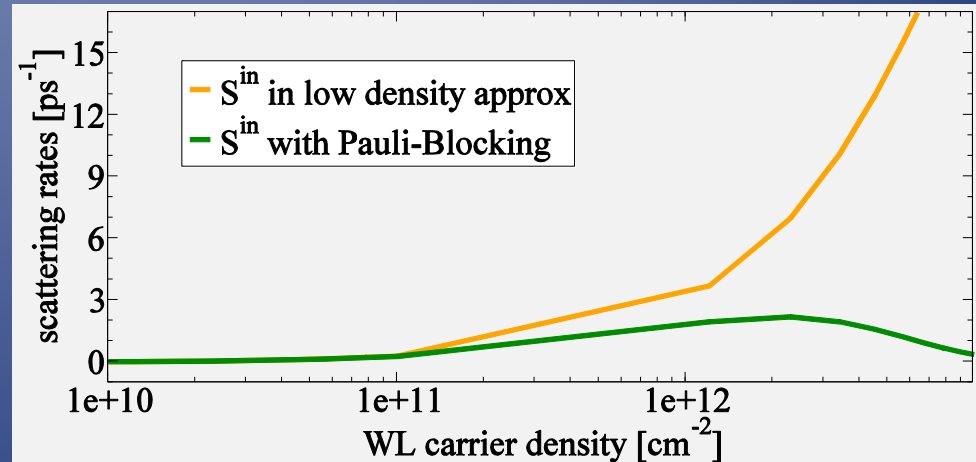
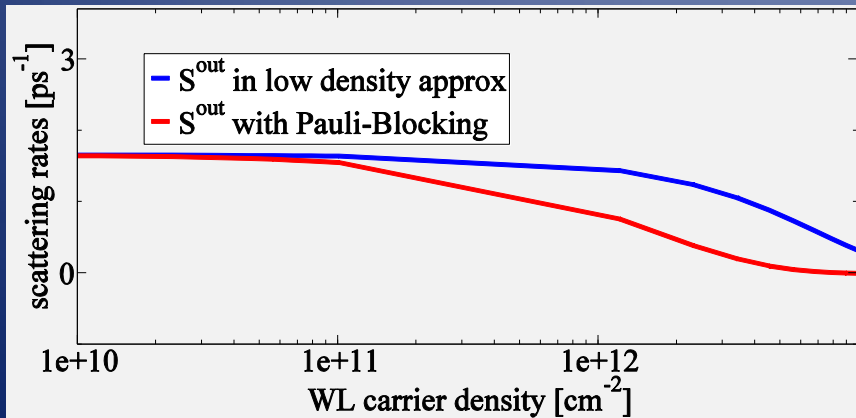
LO-phonon assisted carrier scattering rates depend on carrier density:

Effective Hamiltonian coupling element:

$$g_{r0}^{q'q''} = - \sum_i \frac{\tilde{g}_{ri}^{q'} g_{i0}^{q''} (1 - f_i)}{(\epsilon_i - \epsilon_0 - \hbar\omega_{LO})}$$

Pauli-blocking enters in the total T1-time¹:

$$T_1 = \frac{1}{\Gamma n^2 (1 - f_r) + (n + 1)^2 f_r}$$



Semiconductor Quantum Dot:

□ 3D bulk: Electron-phonon interaction¹:

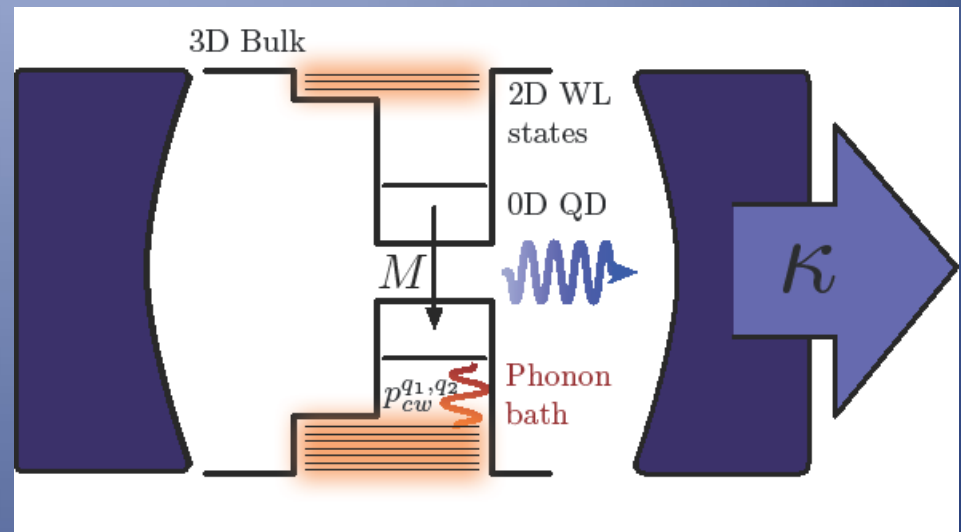
temperature dependent dephasing processes

□ 2D WL: Electron-electron interaction

carrier density dependent pumping rate

□ 0D QD: Electron-photon interaction

strong coupling for single-photon emission



1. Characterization of the system, e.g. via luminescence experiments
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3. **Quantum emission dynamics of QD carriers strongly coupled to a cavity mode¹**

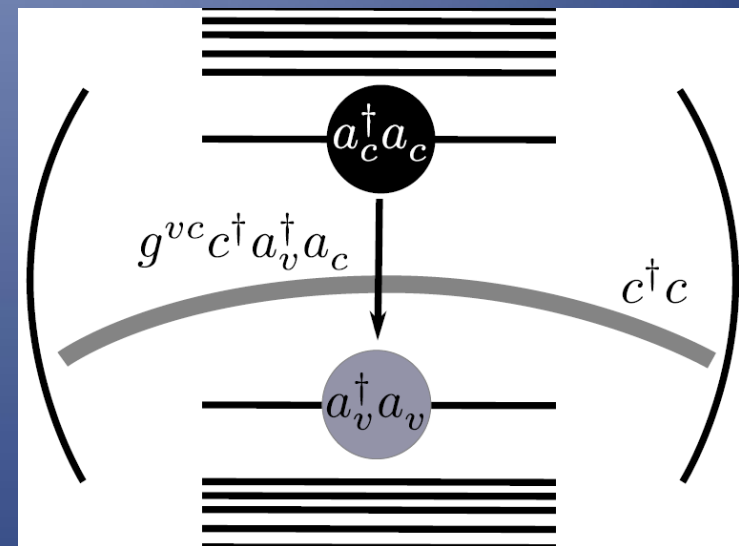
Heisenberg equation of motion approach to treat more interactions

$$-i\hbar\partial_t\langle O \rangle = \langle [H_0 + H_{el-pt}, O] \rangle$$

To reproduce the Jaynes-Cummings model,
 we introduce a factorization approach for strongly correlated systems:
 the photon probability cluster expansion (PPCE).¹

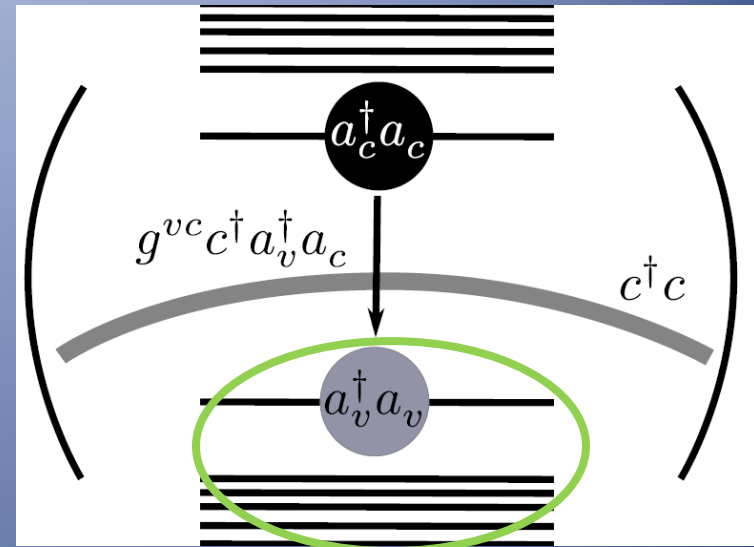
$$p_n = \langle |n\rangle \langle n| \rangle \quad f_n^h = p_n - \langle |n\rangle \langle n| a_v^\dagger a_v \rangle$$

$$\langle c^\dagger c \rangle = \sum_{n=1}^{\infty} n p_n \quad f_n^e = \langle |n\rangle \langle n| a_c^\dagger a_c \rangle$$



Due to the quantum dot-wetting layer interaction, the one-electron assumption is not valid anymore.

$$\langle |n\rangle \langle n | a_1^\dagger a_2^\dagger a_3 a_4 \rangle \neq 0$$



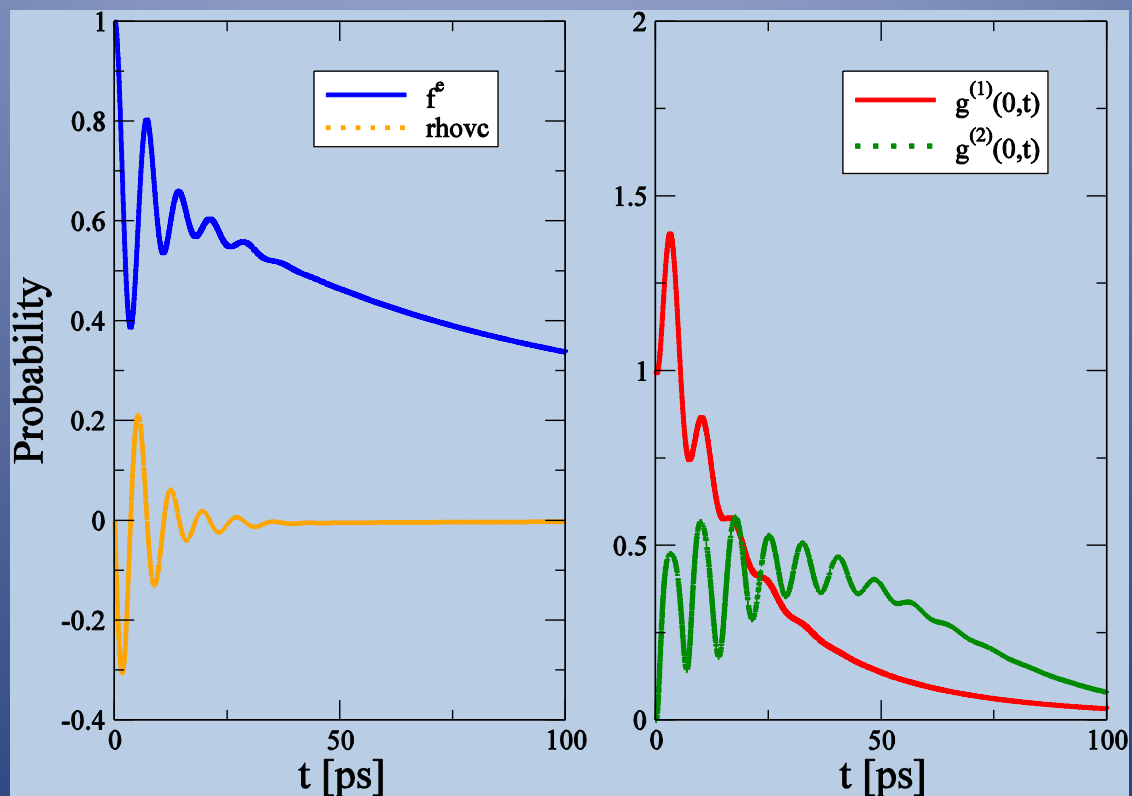
This many-particle contribution is taken into account via the Hartree – Fock approximation

$$\langle a_1^\dagger a_2^\dagger a_3 a_4 \rangle \approx \langle a_1^\dagger a_4 \rangle \langle a_2^\dagger a_3 \rangle - \langle a_1^\dagger a_3 \rangle \langle a_2^\dagger a_4 \rangle$$

Here, we introduce a modified the Hartree – Fock approximation¹:

$$\begin{aligned} \langle |n\rangle \langle n | a_1^\dagger a_2^\dagger a_3 a_4 \rangle &\approx p_n \left\{ \langle \frac{|n\rangle \langle n|}{p_n} a_1^\dagger a_4 \rangle \langle \frac{|n\rangle \langle n|}{p_n} a_2^\dagger a_3 \rangle - \langle \frac{|n\rangle \langle n|}{p_n} a_1^\dagger a_3 \rangle \langle \frac{|n\rangle \langle n|}{p_n} a_2^\dagger a_4 \rangle \right\} \\ &\approx \frac{1}{p_n} \left\{ \langle |n\rangle \langle n | a_1^\dagger a_4 \rangle \langle |n\rangle \langle n | a_2^\dagger a_3 \rangle - \langle |n\rangle \langle n | a_1^\dagger a_3 \rangle \langle |n\rangle \langle n | a_2^\dagger a_4 \rangle \right\} \end{aligned}$$

Rabi-oscillation as strong coupling signature:



without pump mechanism, photon density and electron density decays

Electrically driven QD is a source for single-photons on demand

Electrons scatter into the QD via LO-phonon assisted scattering

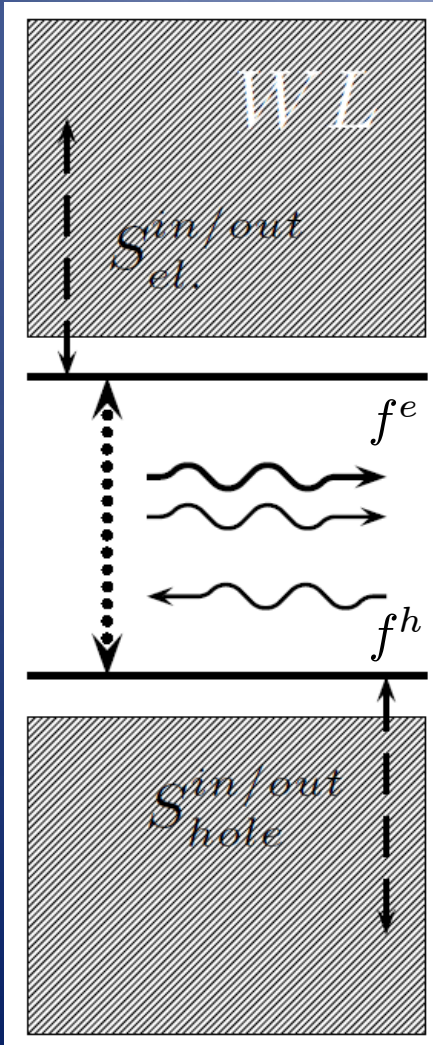
$$\partial_t f_n^e|_{pump} = S_e^{in}(p_n - f_n^e) - S_e^{out} f_n^e$$

$$\partial_t f_n^h|_{pump} = S_h^{in}(p_n - f_n^h) - S_h^{out} f_n^h$$

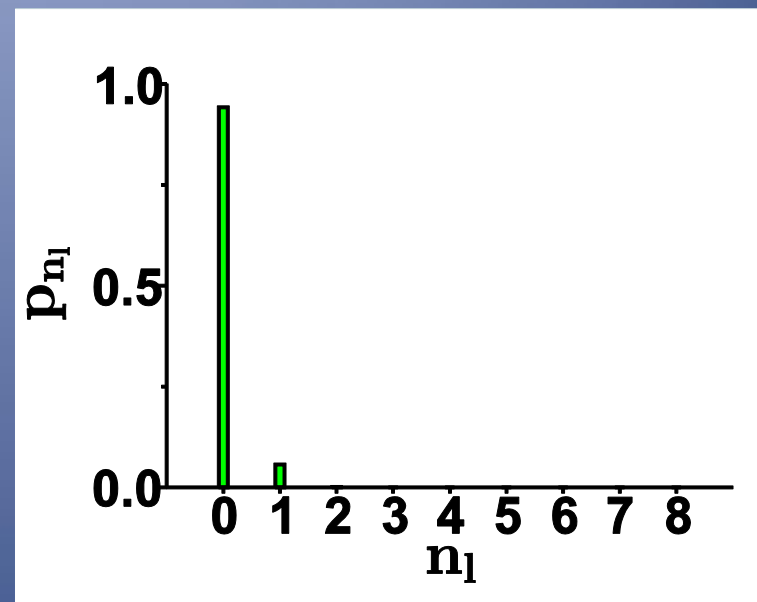
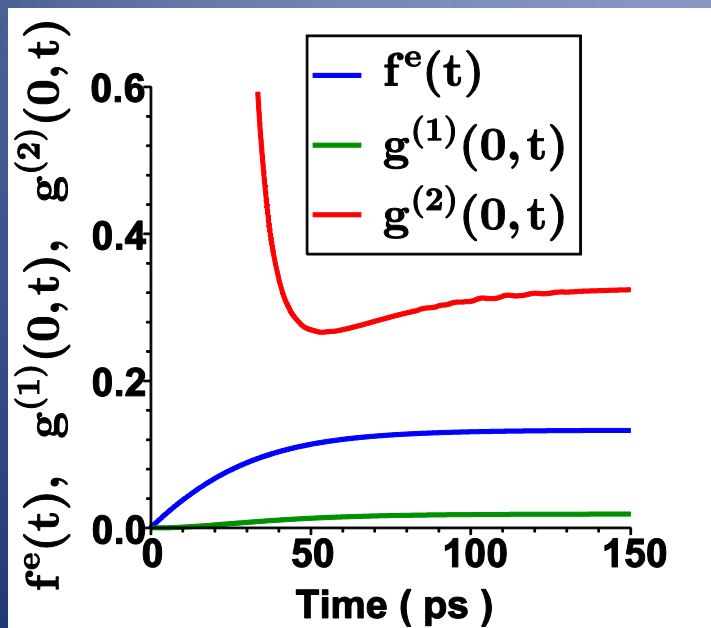
$$\begin{aligned} & \partial_t \langle |n+1\rangle \langle n| a_v^\dagger a_c \rangle |_{pump} \\ &= - \left(\frac{S_e^{in}}{2} + \frac{S_e^{in}}{2} + \frac{S_e^{out}}{2} + \frac{S_h^{out}}{2} \right) \langle |n+1\rangle \langle n| a_v^\dagger a_c \rangle \end{aligned}$$

Derived via effective Hamiltonian approach

Pump mechanism and losses balance into a stationary state¹



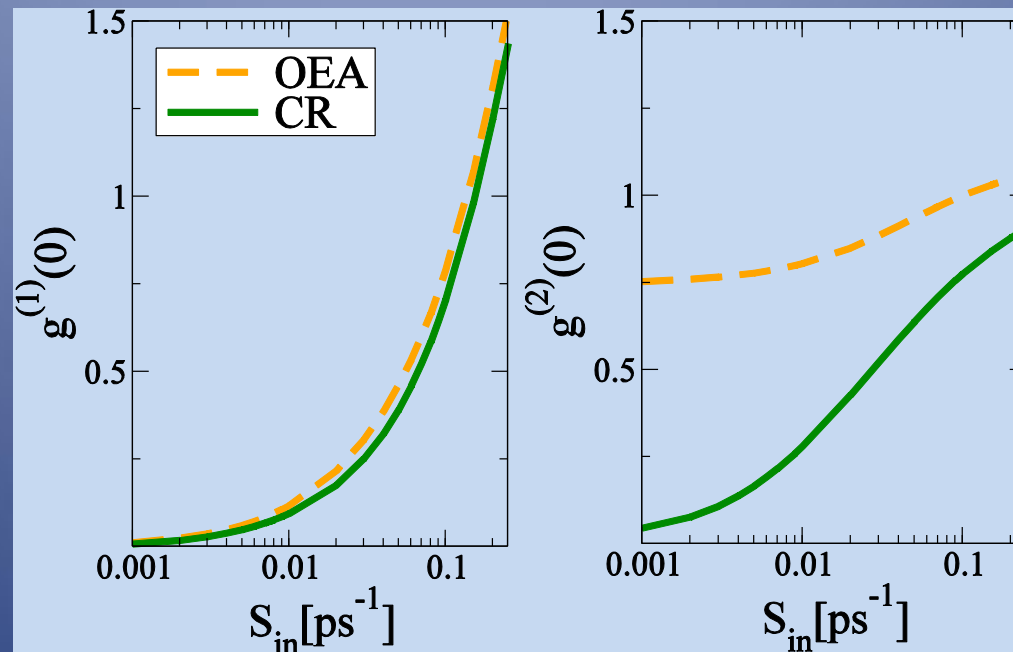
Weak pumping regime: a single-photon source operates in stationary state



Microscopic model includes the different time-scale consistently, and the detailed description of the quantum light correlations via photon-probabilities

Microscopic model reveals: Why QD are very promising single-photon sources

Comparison with one-electron approximation (OEA):



Due to the WL, Pauli-blocking in the QD states occur
Advantageous for single-photon emission in a wide pump interval

Summary

Folie: 19

Summary:

- ❑ Characterization of the system via Raman spectroscopy (**Julia Kabuss**), predicted anti-crossing between Mollow-triplett and LO-phonon peak

- ❑ LO-phonon assisted carrier scattering rates (**Matthias-Rene Dachner**), decreased T1-time due to Pauli-blocking

- ❑ Few photon model for quantum light emission (**Alexander Carmele**), modified Hartree-Fock factorization

- ❑ Electrically driven single-photon emitter (**Yumian Su**), advantageous Pauli-blocking in semiconductor single-photon sources

thank you!!



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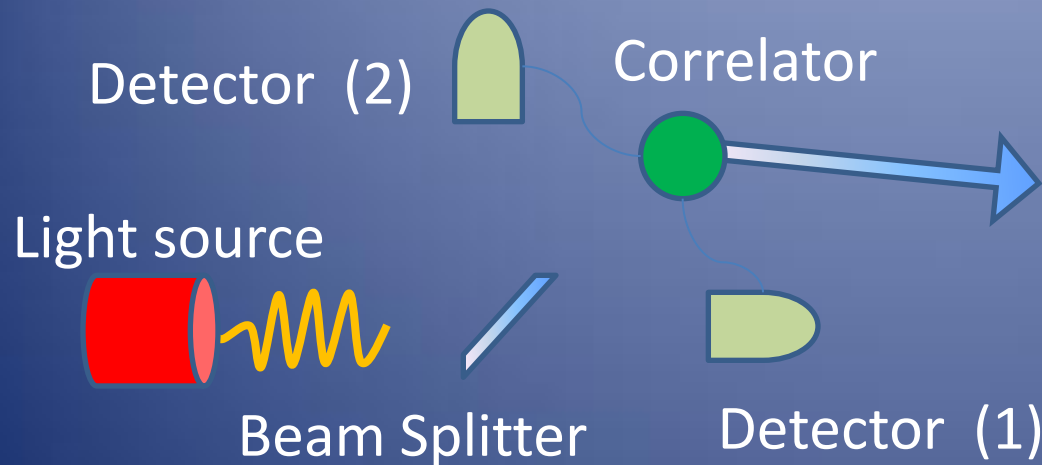
10th International Conference on
Numerical Simulation of Optoelectronic Devices September 6-9, 2010

31.08.2010

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Folie: 21

Hanbury Brown – Twiss Experiment: Intensity correlation



$$\begin{aligned}
 g^{(2)} &= \frac{\langle c^\dagger c^\dagger c c \rangle}{\langle c^\dagger c \rangle^2} \\
 &= \frac{\langle (\Delta n)^2 \rangle - \langle n \rangle}{\langle n \rangle^2} + 1
 \end{aligned}$$

- Does the probability to measure a photon at Detector (1) change the probability to measure a photon at Detector (2) and vice versa?